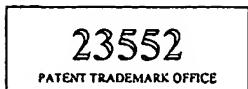


FORM 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION <small>(Use several sheets if necessary)</small>			Docket Number: 10873.0884USDI	Application Number: filed here within
			Applicant: Yorito OTA	
			Filing Date: filed here within	Group Art Unit: n/a

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
<i>GJL</i>	US 6,221,685	April 2001	ICHINOSE et al.			
	US 5,557,118	Sept. 1996	HASHIMOTO			
	US 6,154,475	Nov. 2000	SOREF et al.			
	US 5,270,554	Dec. 1993	Palmour			
	US 4,762,806	Aug. 1988	Suzuki et al.			
<i>SM</i>	US 5,905,277	May 1999	Ota et al.			

FOREIGN PATENT DOCUMENTS						
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
						YES
<i>GJL</i>	JP 6-97107	April 1994	Japan			
	JP 5-102497	April 1993	JAPAN			
	JP 5-175239	July 1993	JAPAN			Abstract
	JP 2000-101099	April 2000	JAPAN			Abstract
	JP 60-142568	July 1985	JAPAN			Abstract
	JP 10-321646	Dec. 1998	JAPAN			Abstract
<i>SM</i>	JP 5-90572	April 1993	JAPAN			Abstract

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)		
<i>GJL</i>		"Nickel and Molybdenum Ohmic Contacts on Silicon Carbide", Institute of Physics Conference Series No. 142, pp 577-580, 1996.



EXAMINER	<i>S. Suttor</i>	DATE CONSIDERED	<i>3/18/05</i>
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.			